



Ultrahigh-Speed Switching Applications

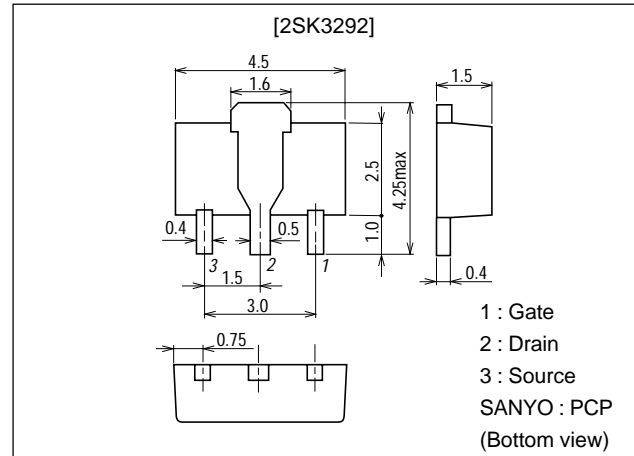
Features

- Low ON resistance.
- Ultrahigh-speed switching.
- 4V drive.

Package Dimensions

unit:mm

2062A



Specifications

Absolute Maximum Ratings at Ta = 25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|-----------------------------|-----------|--|-------------|------|
| Drain-to-Source Voltage | V_{DS} | | 60 | V |
| Gate-to-Source Voltage | V_{GS} | | ± 20 | V |
| Drain Current (DC) | I_D | | 2 | A |
| Drain Current (Pulse) | I_{DP} | $PW \leq 10\mu s$, duty cycle $\leq 1\%$ | 8 | A |
| Allowable Power Dissipation | P_D | Mounted on a ceramic board (250mm ² ×0.8mm) | 1.5 | W |
| | | $T_c = 25^\circ C$ | 3.5 | W |
| Channel Temperature | T_{ch} | | 150 | °C |
| Storage Temperature | T_{stg} | | -55 to +150 | °C |

Electrical Characteristics at Ta = 25°C

| Parameter | Symbol | Conditions | Ratings | | | Unit |
|--|---------------|-----------------------------------|---------|-----|----------|-----------|
| | | | min | typ | max | |
| Drain-to-Source Breakdown Voltage | $V_{(BR)DSS}$ | $I_D = 1mA$, $V_{GS} = 0$ | 60 | | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 60V$, $V_{GS} = 0$ | | | 10 | μA |
| Gate-to-Source Leakage Current | I_{GSS} | $V_{GS} = \pm 16V$, $V_{DS} = 0$ | | | ± 10 | μA |
| Cutoff Voltage | $V_{GS(off)}$ | $V_{DS} = 10V$, $I_D = 1mA$ | 1.0 | | 2.4 | V |
| Forward Transfer Admittance | $ y_{fs} $ | $V_{DS} = 10V$, $I_D = 1A$ | 1.5 | 2.1 | | S |
| Static Drain-to-Source On-State Resistance | $R_{DS(on)1}$ | $I_D = 1A$, $V_{GS} = 10V$ | | 240 | 320 | $m\Omega$ |
| | $R_{DS(on)2}$ | $I_D = 1A$, $V_{GS} = 4V$ | | 320 | 440 | $m\Omega$ |

Marking : KY

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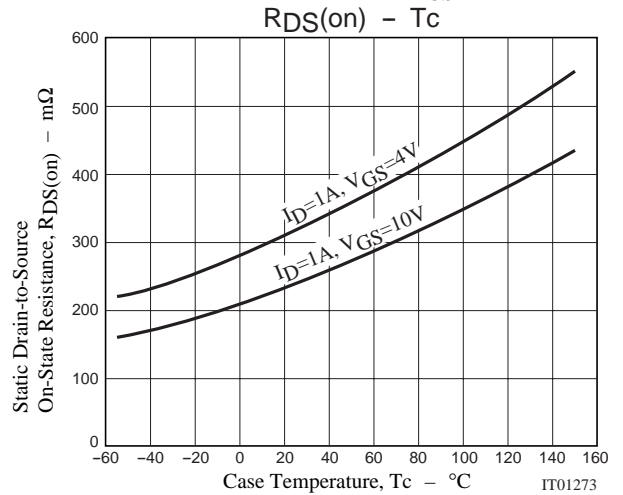
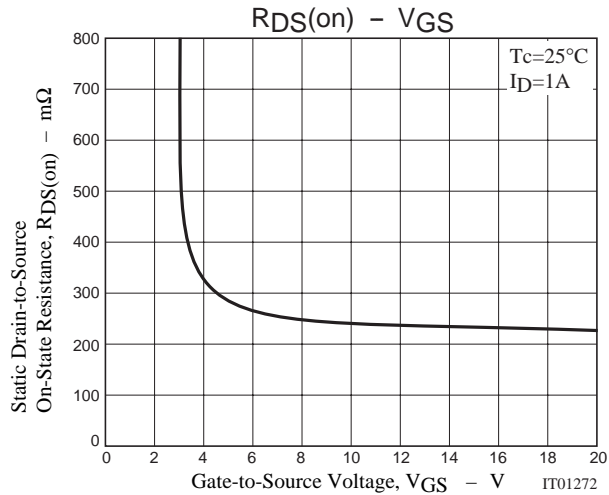
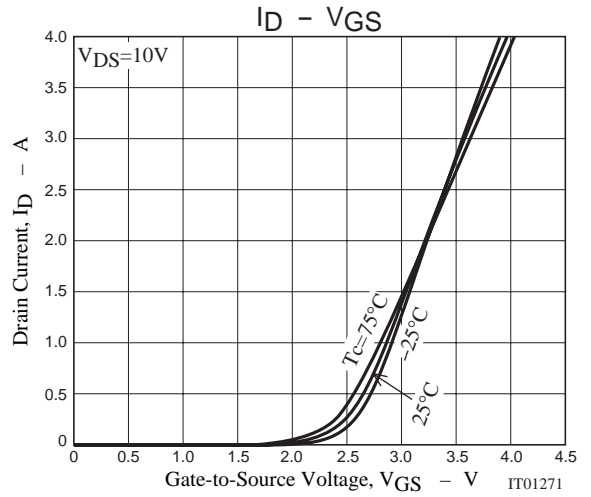
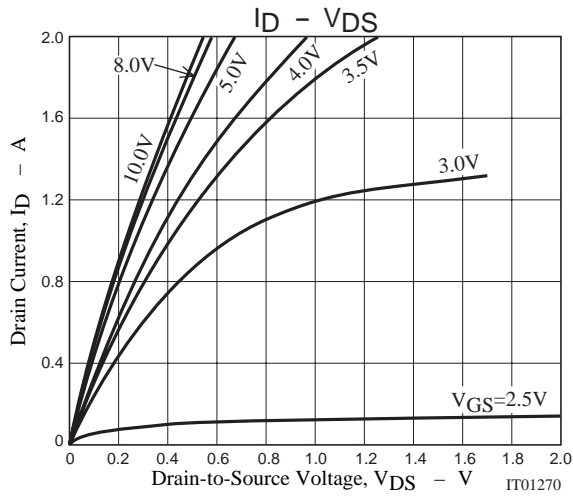
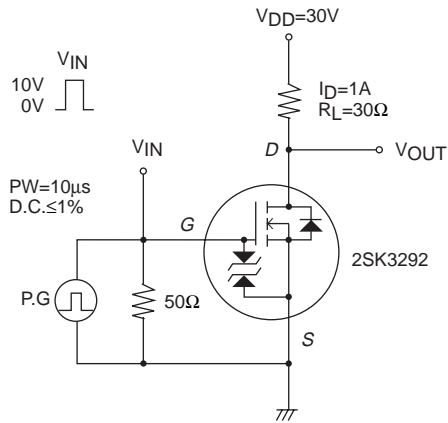
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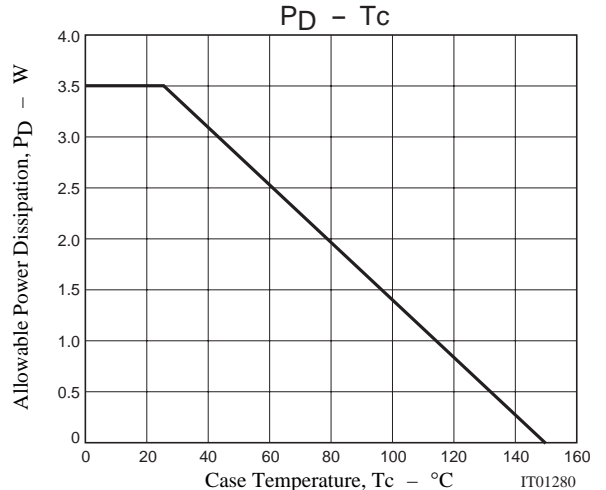
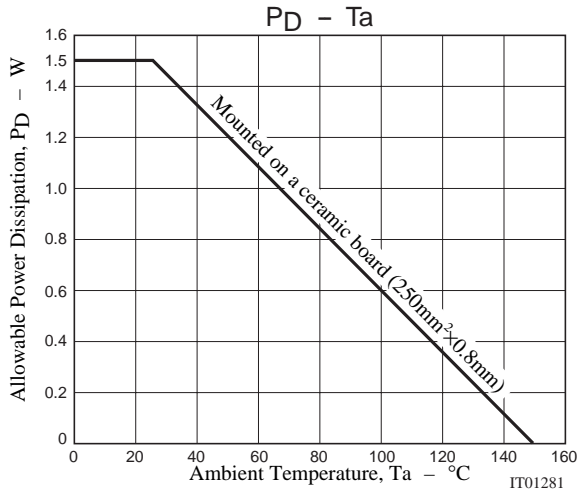
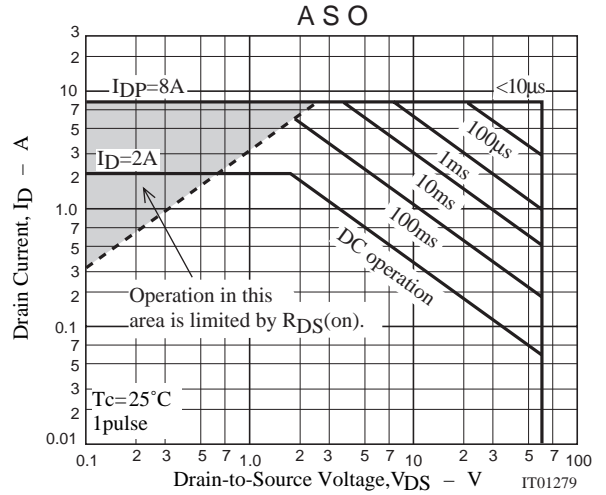
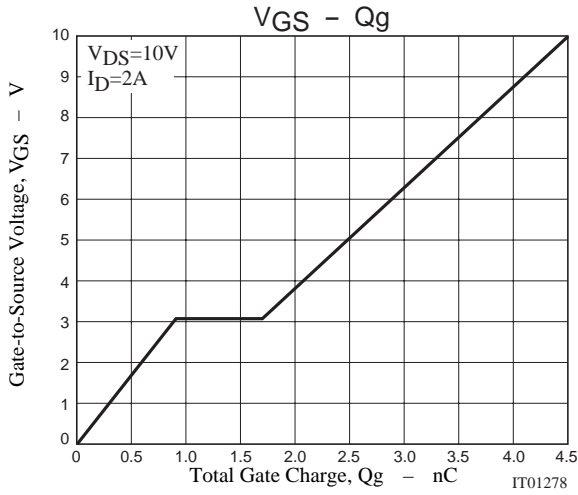
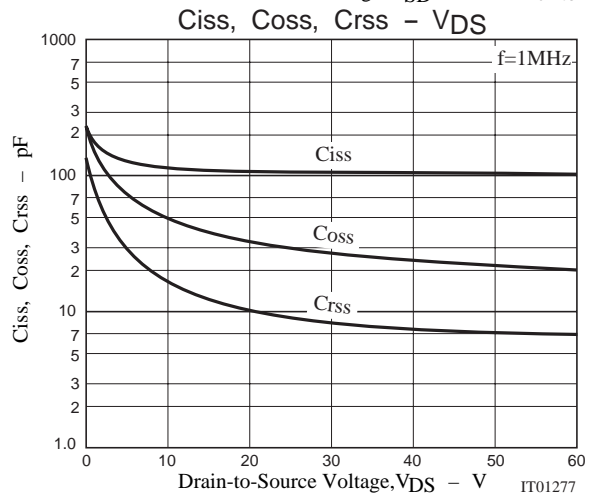
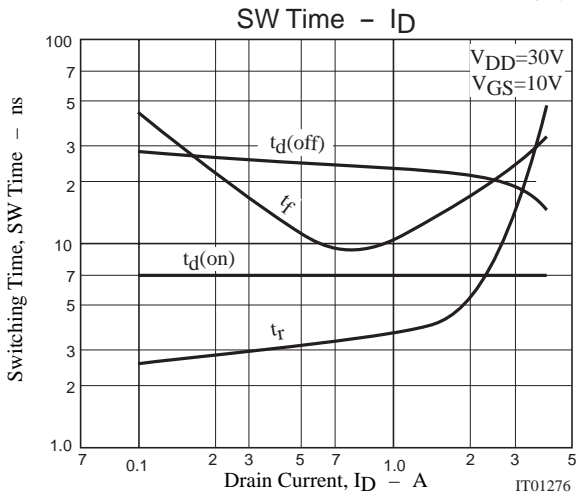
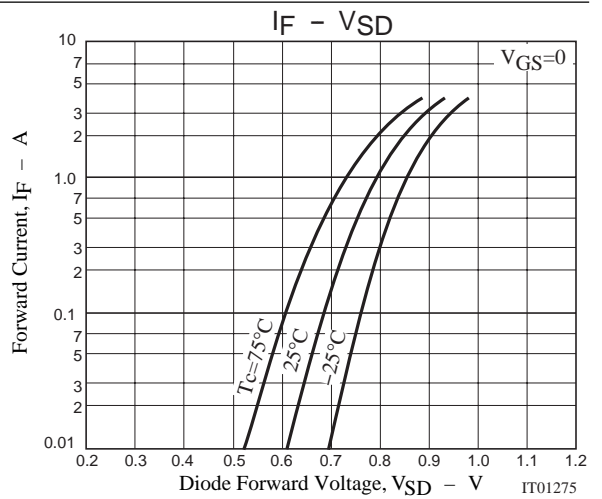
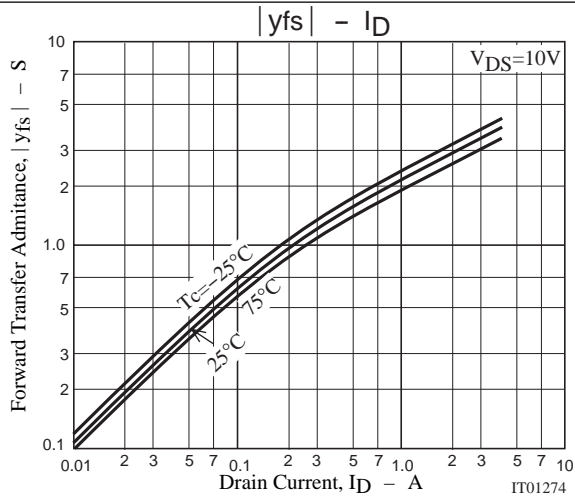
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| Parameter | Symbol | Conditions | Ratings | | | Unit |
|-------------------------------|---------------------|--|---------|------|-----|------|
| | | | min | typ | max | |
| Input Capacitance | C _{iss} | V _{DS} =20V, f=1MHz | | 110 | | pF |
| Output Capacitance | C _{oss} | V _{DS} =20V, f=1MHz | | 35 | | pF |
| Reverse Transfer Capacitance | C _{rss} | V _{DS} =20V, f=1MHz | | 10 | | pF |
| Turn-ON Delay Time | t _{d(on)} | See specified Test Circuit | | 7 | | ns |
| Rise Time | t _r | See specified Test Circuit | | 4 | | ns |
| Turn-OFF Delay Time | t _{d(off)} | See specified Test Circuit | | 24 | | ns |
| Fall Time | t _f | See specified Test Circuit | | 11 | | ns |
| Total Gate Charge | Q _g | V _{DS} =10V, V _{GS} =10V, I _D =2A | | 4.5 | | nC |
| Gate-to-Source Charge | Q _{gs} | | | 0.9 | | nC |
| Gate-to-Drain "Miller" Charge | Q _{gd} | | | 0.8 | | nC |
| Diode Forward Voltage | V _{SD} | I _S =2A, V _{GS} =0 | | 0.85 | 1.2 | V |

Switching Time Test Circuit



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